

MESFET HIGH IP³ MIXER

SURFACE MOUNT MODEL: SFM-2A-1

OPTIMIZED BANDWIDTH

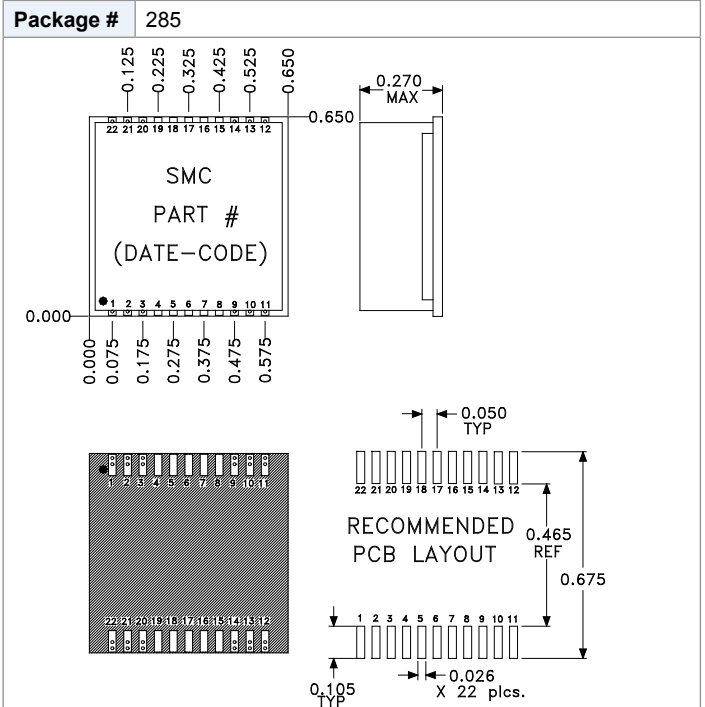
FEATURES:

- ▶ High Performance
- ▶ High IP³
- ▶ Small Size, Surface Mount
- ▶ RoHS Compliant
- ▶ Lead Free REL-PRO[®] Technology



SPECIFICATIONS (Rev. C 09/01/06)

Frequency	LO (MHz)	RF (MHz)	IF (MHz)
	89 - 116	19 - 41	70 - 96
Conversion Loss (dB)	Typ.	Max.	
	6.5	8.5	
RF/IF Isolation (dB)	Typ.	Min.	
	30	20	
LO Rejection (dBc)	RF	Typ.	Min.
		40	25
	IF	Typ.	Min.
		25	15
LO Power	0 dBm (Nom.)		
1 dB Comp. Pt.	+23 dBm (Typ.)		
Input IP ³	+40 dBm (Typ.)		
Vdd	+4.3 to 4.5 Volts @ 80 mA (Max.)		
Impedance	50 Ohms (Nom.)		
Operating Temperature Range	-20 to +70 °C		
<i>Note: Isolation values apply for Sinewave L.O. signals.</i>			



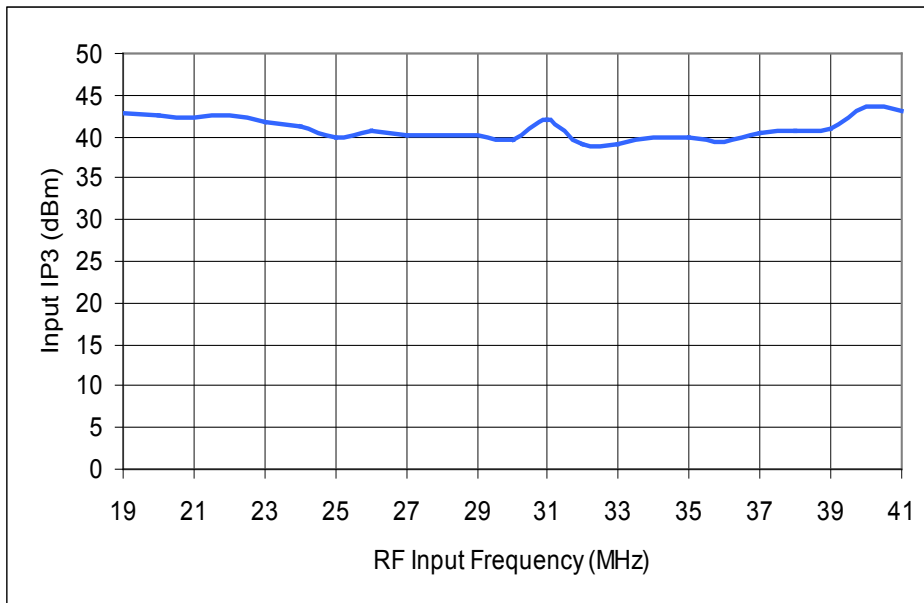
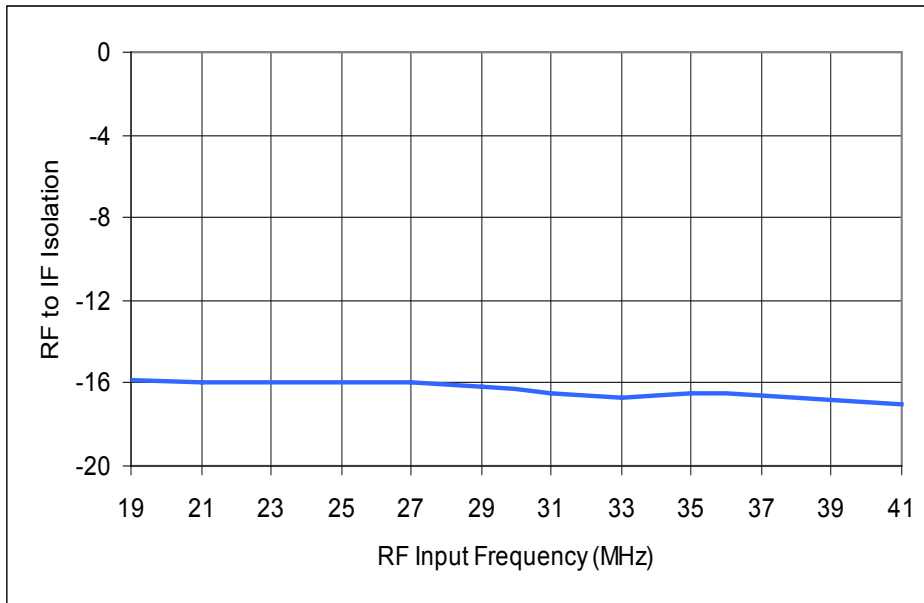
PORT LOCATION				
RF	LO	IF	Vdd	GND
21	13	2	10	All Others

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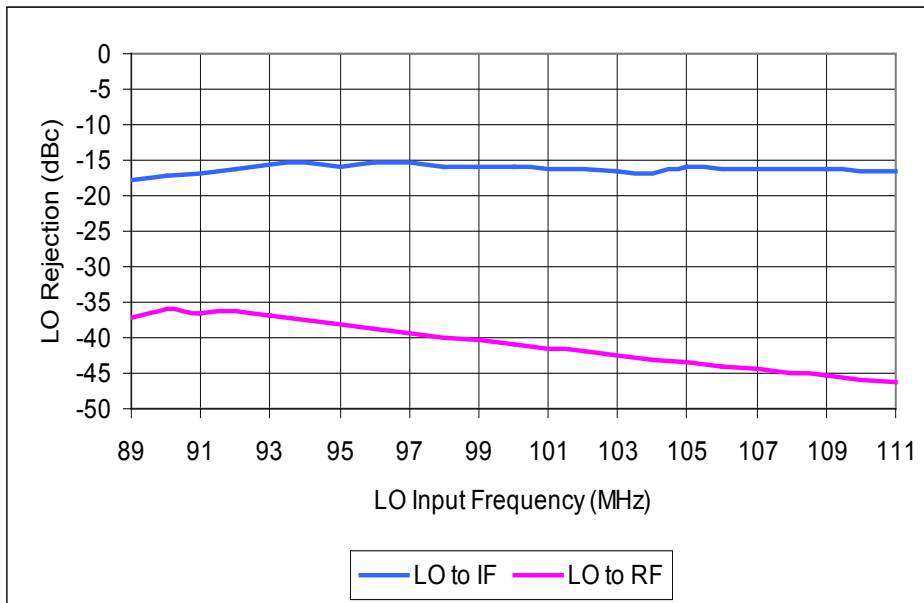
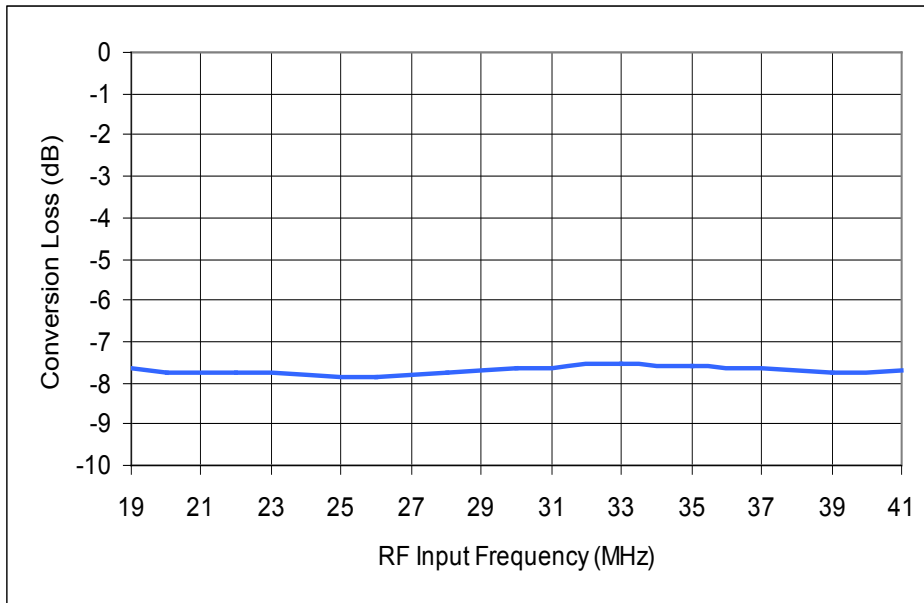


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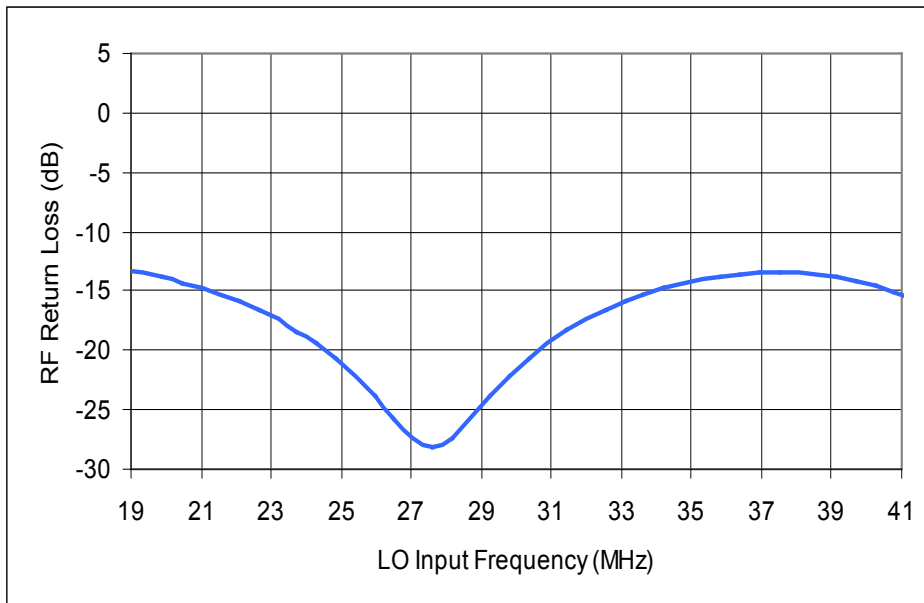
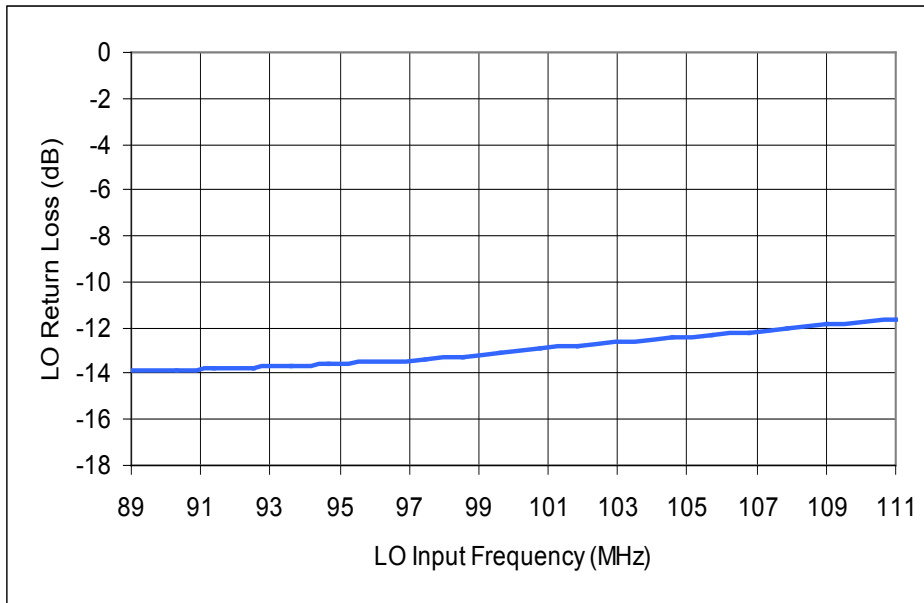


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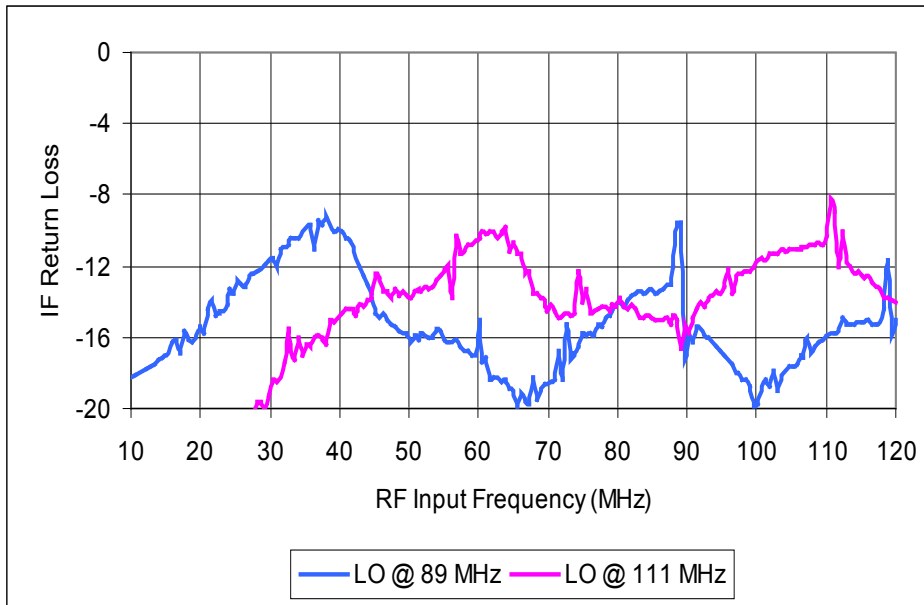
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